

Time: 3 Hours

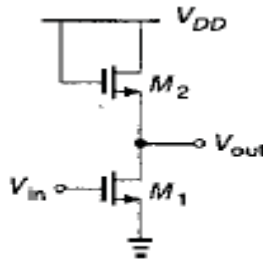
Max Marks: 80

- N.B. 1) Question No.1 is compulsory  
2) Solve any three questions from the remaining questions.  
3) Assume suitable data if necessary.

1 Solve any four of the following.

- (a) Explain trade-offs in analog design with the help of analog design octagon 5
- (b) For a n-channel MOSFET draw- a) a basic small signal model b) small signal model considering channel length modulation effect c) small signal model considering body effect 5
- (c) Explain the concept of clock feed through in the MOSFET sampling circuit 5
- (d) Compare performance of various op-amp topologies 5
- (e) Derive expression for input referred noise of CS stage 5

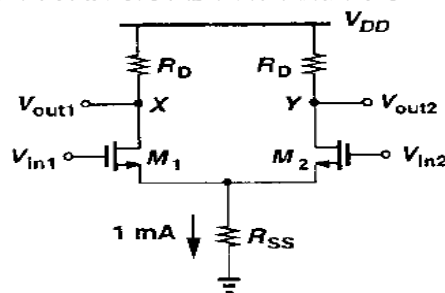
2 (a) 10



Identify the above network. Derive the gain equation of the above circuit.

- (b) Derive equation of differential gain, common mode gain and CMRR of a differential amplifier circuit. 10

3 (a) The following circuit uses a resistor rather than a current source to define a tail 10

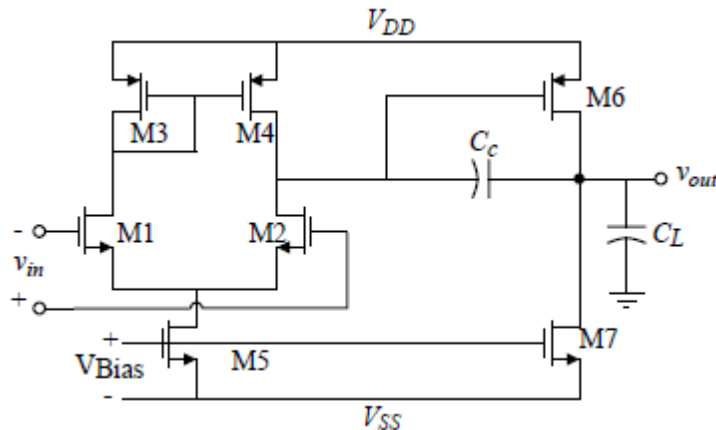


current of 1mA.

Assume  $(W/L)_{1,2} = 25/0.5$ ,  $\mu_n C_{ox} = 50 \mu A/V^2$ ,  $V_{TH} = 0.6V$ ,  $\lambda = 0$ ,  $V_{DD} = 3V$

- (a) What is the required input CM for which  $R_{SS}$  sustains 0.5V? 10
- (b) Calculate  $R_D$  for a differential gain of 5
- (c) What happens at the output if input CM level is 50mV higher than the value calculated in (a)?
- (b) Derive expression for voltage gain  $A_v$  and output resistance  $R_o$  of source follower stage.

Q.4 Design two stage operational amplifiers that meet the following specifications 20



$$A_v > 3000V/V \quad V_{DD} = 2.5V \quad V_{SS} = -2.5V$$

Gain Bandwidth = 5MHz, Slew Rate  $> 10V/\mu s$ ,  $60^\circ$  phase margin,

$$0.5V < V_{out} \text{ range} < 2V,$$

$$ICMR = -1.25V \text{ to } 2V,$$

$$P_{diss} \leq 2 \text{ mW}, C_L = 10pF$$

$$\text{Use } K_N' = 100\mu A/V^2, K_P' = 20\mu A/V^2, V_{TN} = |V_{TP}| = 0.5V, \lambda_N = 0.06V^{-1},$$

$$\lambda_P = 0.08V^{-1}, C_{ox} = 2.47fF/\mu m^2.$$

Verify that the designed circuit meets required voltage gain and power dissipation specifications

5 (a) Explain the charge injection mechanism in MOS sampling circuits and also describe the errors contributed by the above effect. 10

(b) What is a band gap reference? Describe methods of implementation of band gap references 10

6 Write short note on any four

(a) Necessity of Millers theorem 5

(b) Gilbert Cell 5

(c) Charge Pump PLL 5

(d) Comparison of full custom design and semi custom design 5

(e) Performance parameters of VCO 5

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